

Photonic Integration for Space Applications

September 14. 2022, EPIC Meeting on Photonics at the Final Frontier at European Space Agency (ESA)

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Heterogeneous systems, based on new paradigms in computing, communication and sensing, will become the key enabler of our sustainable information society, thereby addressing our global societal challenges



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Photonic integration: optical chips







Advantages of photonic integration

increased performance

in terms of stability, speed and sensitivity, improves electronics performance;

decreased size, weight and power (SWaP)

for use in, e.g., drones, space and aircraft, handheld and wearable devices;

decreased cost

at high volumes due to wafer-scale manufacturing.



100 Gbps transmitter R. Nagarajan, Infinera, 2006



"Moore's Law" of Photonics





More in detail: InP PICs



Electronic integration

A

Optical Amplifier

Phase Modulator

Polarisation Converter

Waveguide

integration



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TU/e

Building blocks to make a circuit



Smit et al., Semiconductor Science and Technology 29, 8 (2014)



Wafers with many circuits





Jeppi പല്പ The ecosystem Knowledge Over 500 PIC designs realised in JePPIX foundries Variety of THz and RF circuits Lasers Medical and bio-imaging mi 🍣 Optical data handling Sensor readout units QKD transceivers THE R P. LEWIS CO., NAME OF TAXABLE PARTY. Microwave photonics beam-former Optical switching Fibre to the home

New pilot line services launched with manufacturing-grade PDKs and test automation







Photonic integrated circuit foundry **to your design** with 15-year track record

Trusted supply chain with foundry-calibrated design

Turn-key solutions for design, mass-manufacture, and automated test

Accelerated development programs with integrated design loops

Comprehensive components including lasers and amplifiers

Seamlessly from idea to small series and mass production

jeppix.eu/pilotline pilotline@jeppix.eu

Converge on three major integration platforms

	Si ₃ N ₄ SiO ₂ Si	Si BOX Si	InP InGaAs InP
	silica / silicon nitride	silicon-on-insulator	indium phosphide
wavelength range	0.3 μm – 3 μm	1.1 μm – 4.5 μm	1.3 μm – 1.6 μm
lasers, amplifers	NA	NA	+++
photodetectors	NA	++	+++
modulators	NA	+	++
passive devices	+++	++	+
wafer level packaging	+++	+++	NA
electronic SoC and SiP integration	+++	+++	NA



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electronic SoC and SiP integration	+++	+++	NA



Combine – laser micro-package





credits: Chipworks



Combine – hybrid integration





Far-Brusatori at al., OL 2022



Combine – heterogeneous integration



- III/V wafer or die bonded to processed silicon
 → no alignment;
- Back-end process on silicon substrates → CMOS infrastructure compatible;
- Mode couples to III/V → optical gain, detection or modulation.



Combine – micro-transfer printing



credits: INSPIRE – H2020



Hybrid and heterogeneous integration



	LaMP	Flip-chip	Wafer-bond	Micro-TP
InP PIC maturity	×	✓	On target wafer	 ✓
Optical coupling efficiency	×	 Image: A set of the set of the	×	 Image: A set of the set of the
Waveguide in-out devices	None	 Image: A set of the set of the	✓	 ✓
Wafer level test and assembly	 Image: A set of the set of the	 Image: A set of the set of the	On target wafer	
Burn in	 ✓ 	 Image: A set of the set of the	On target wafer	 Image: A start of the start of
Population of InP devices	Sequential	Sequential	 ✓ 	 ✓
Laser performance	✓	 ✓ 	 ✓ 	 ✓
Back end process integration	✓	 Image: A set of the set of the	Substrate removal	
Density and volume	Micro-optics	Solder pad limit	 ✓ 	 ✓
Reduced barriers for new PICs	 	 	 	 ✓

17 prof. Martijn J. R. Heck – Scientific Director



Additional flavors – other wavelengths



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multi-octave spectral beam combiner prof. Martijn J. R. Heck – Scientific Director



Silicon Substrate



 $2.0\,\mu m$ inP on Si laser



Additional flavors – electronics







3" InP PIC wafer from HHI bonded to laser-sawn BiCMOS wafer from NXP

Intimate co-design to remove components and parasitics Systematically improve efficiency, speed, and information density Using wafer scale processes

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http://wipe.jeppix.eu



Applications in space

- wireless and optical communication;
- optical atomic clock;
- gyroscope;
- fiber sensors (temperature, integrity);
- optical frequency combs;
- microwave photonics oscillators, signal processing, ...
- ... and many more!



Photonics-based beamforming antenna system for broadband satellite communication, LioniX International.



Conclusion

- monolithic PIC platforms mature and accessible;
- hybrid/heterogeneous integration, assembly and packaging on the rise;
- more opportunities coming up by integration with electronics and other III-Vs (UV, visible, near-IR, mid-IR, THz, RF, ...)

Technology ecosystem ready for "PICs in space"... but design is another story...





Eindhoven Hendrik Casimir Institute – EHCI



https://www.tue.nl/en/research/institutes/eindhoven-hendrik-casimir-institute/



Optical chips miniaturize optical systems





https://www.photonfirst.com/



The engineering vs. physics trade-off





